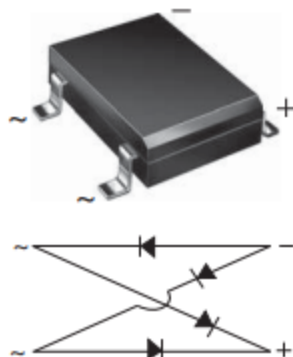


# Miniature Glass Passivated Single-Phase Surface Mount Bridge Rectifiers



Case Style DFS

## FEATURES

- UL recognition, file number E54214
- Ideal for automated placement
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see

## TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

## MECHANICAL DATA

**Case:** DFS

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked on body

PRIMARY CHARACTERISTICS	
Package	DFS
$I_{F(AV)}$	1 A
$V_{RRM}$	50 V, 100 V, 200 V, 400 V, 600 V, 800 V, 1000 V
$I_{FSM}$	50 A
$I_R$	5 $\mu$ A
$V_F$ at $I_F = 1.0$ A	1.1 V
$T_J$ max.	150 °C
Diode variations	Quad

MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise noted)									
PARAMETER	SYMBOL	DF005S	DF01S	DF02S	DF04S	DF06S	DF08S	DF10S	UNIT
Device marking code		DF005S	DF01S	DF02S	DF04S	DF06S	DF08S	DF10S	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward output rectified current at $T_A = 40$ °C <sup>(1)</sup>	$I_{F(AV)}$	1.0							A
Peak forward surge current single half sine-wave superimposed on rated load	$I_{FSM}$	50							A
Rating for fusing ( $t < 8.3$ ms)	$I^2t$	10							A <sup>2</sup> s
Operating junction and storage temperature range	$T_J, T_{STG}$	- 55 to + 150							°C

### Note

<sup>(1)</sup> Units mounted on PCB with 0.51" x 0.51" (13 mm x 13 mm) copper pads

ELECTRICAL CHARACTERISTICS ( $T_A = 25$ °C unless otherwise noted)										
PARAMETER	TEST CONDITIONS	SYMBOL	DF005S	DF01S	DF02S	DF04S	DF06S	DF08S	DF10S	UNIT
Maximum instantaneous forward voltage drop per diode	1.0 A	$V_F$	1.1							V
Maximum DC reverse current at rated DC blocking voltage per diode	$T_A = 25$ °C	$I_R$	5.0							$\mu$ A
	$T_A = 125$ °C		500							
Typical junction capacitance per diode <sup>(1)</sup>		$C_J$	25							pF